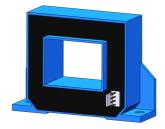
Hall effect Current Sensor

SCK18





Product description:

Features

- Based on the Hall effect measurement principle, open loop circuit method.
- The isolation voltage between primary and secondary is greater than 5000VAC.
- Designed according to UL94-V0 flame retardant rating.
- Using automatic adjustment technology, product performance is better.

Performance

- Can measure DC, AC, pulse, and various irregular waveforms under isolated conditions.
- Wide measurement range, fast response speed, low zero drift, low temperature drift, high accuracy and good linearity.
- Dynamic performance (di/dt and response time) is optimal when the busbar is fully filled with primary perforations.
- Strong ability to resist external electromagnetic interference (BCI, EFT, CS, CE, ESD, dv/dt, etc.).

Application

It can be widely used in inverters, UPS, photovoltaic inverters, electric vehicle drives, high-frequency power supplies, inverter welding machines and other products.

Implementation standards

- GB/T 7665-2005
- JB/T 7490-2007
- JB/T 25480-2010
- JB/T 9473-2020
- SJ 20792-2000

Certifications











Technical Parameters

Model	SCK18-						
Parameters (25°C)	400A	500A	600A	800A	1000A	1200A	1500A
Primary Current (A)I _{PN}	400A	500A	600A	800A	1000A	1200A	1500A
Primary Current Max. Peak Value (A) I _{PM}	±1200A	±1500A	±1800A	±2400A	±2400A	±2400A	±2400A
Output voltage (V) $V_{out} @\pm I_{PN}, \\ R_L = 10 K\Omega$				±4V±1%			

Electrical Data

Item	Min.	Typical.	Max.	Unit
Input power supply voltage range Vc (±5%) (Remark 1, Remark 2)	±11	±15	±18	V _{DC}
Current consumption Ic	-	±15	±20	mA
Withstand resistance R _{INS} @500V DC	1000	-	-	ΜΩ
Output voltage Vout @ I_{PN} , $R_L=10K\Omega$, $T_A=25^{\circ}C$	3.960	4.000	4.040	V
Output internal resistance R _{OUT}	-	102	-	Ω
Load Resistance R _L (Remark 3)	1	10	-	ΚΩ
Accuracy X @I _{PN} , T _A = 25 °C	-	±1	-	%
Linearity ε_L @ R_L =10K Ω , T_A = 25°C	-	±0.5	-	%I _{PN}
Offset voltage $V_{OE}@T_A=25^{\circ}C$	-	±10	±20	mV
Hysteresis voltage V _{OM} @ I _{PN} →0	-	±10	±20	mV
Temperature Coefficient of Offset Voltage TCV _{OE}	-	±0.5	±1	mV/°C
Output voltage temperature coefficient TCV _{out}	-	±0.05	±0.1	%/°C
Response time $t_D @ 0 \rightarrow I_{PN}$	-	3	5	us
Ambient operating temperature T _A	-40	25	125	$^{\circ}$
Ambient storage temperature T _s	-40	25	125	$^{\circ}$
Withstand voltage V _D @50Hz,60s,0.1mA		5000		V _{AC}
Weight m		260		g

Remarks:

1. If VC is less than the minimum value, the measurement will be inaccurate. If VC is greater than

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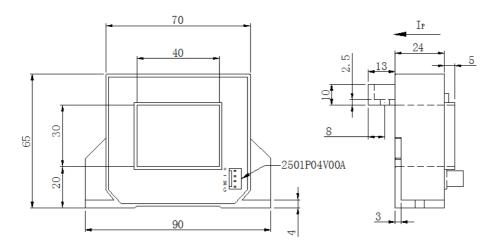
2. When $\pm 12V < V_{CC} < \pm 15V$, will reduce the measurement range.

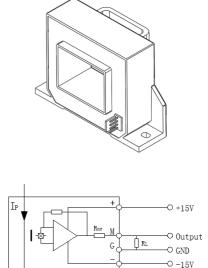
$$V_{OUT} = 4.00 * \frac{R_L}{102 + R_L} * \frac{I_P}{I_{PN}} + V_{OE}$$

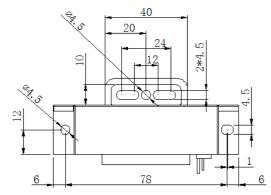
4. di/dt > 50A/uS

Dimensions (in mm)

SCK18

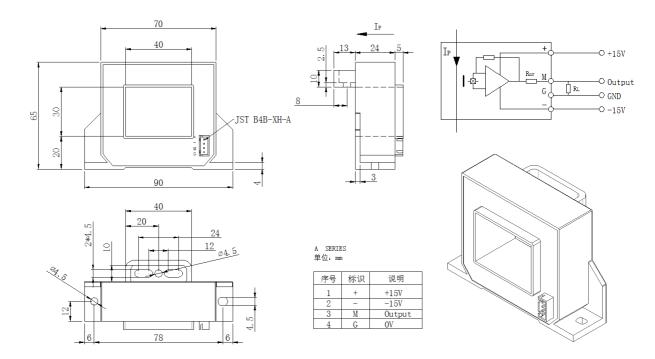






序号	标识	说明
1	+	+15V
2	-	-15V
3	M	Output
4	G	OV

SCK18A



Notes:

1. Size error: ± 1 mm;

2. Primary aperture: □40*30mm;

3. Fastening hole: φ4.5mm*2;

4. The output terminal of SCK18 Series is 2501P04V00A;

The output terminals of SCK18A is JST B4B-XH-A.

5. The IP indication direction is the positive direction of the current;

6. The temperature of the primary conductor shall not exceed 105°C;